NSN 5961-01-251-1435

No Fiig: A110a0



Unitized Semiconductor Devices - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-251-1435 **Inclosure Material:** Metal **Overall Length:** 0.175 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.352 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-78 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 25.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source all transistor and 5.0 gate to source cutoff voltage all transistor **Current Rating Per Characteristic:** 40.00 milliamperes zero-gate-voltage drain current all transistor **Power Rating Per Characteristic:** 367.0 milliwatts total device dissipation all transistor **Terminal Type And Quantity:** 8 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**